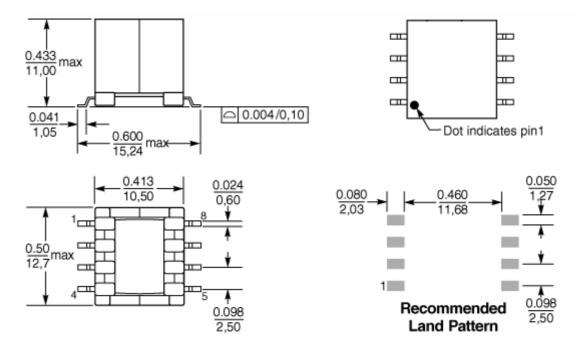


SMT PoE Transformers ~ EP10XFS-LF SERIES

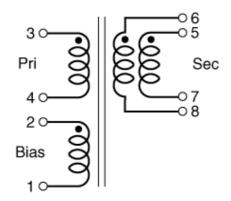


PART NUMBERING SYSTEM

SHAPES AND DIMENSIONS



SCHEMATIC



Secondary windings to be connected in parallel on the PC board



SMT PoE Transformers ~ EP10XFS-LF SERIES



FEATURES

- Developed for Powered Devices in IEEE 802.3af compliant PoE applications
- 36 72 V input. Versions with versions for 7 Watt output
- Designed to operate in continuous mode
- Bias winding output: 12 V, 20 mA
- 250 kHz switching frequency
- 1500 Vrms winding to winding isolation
- **RoHS-compliant.** 260°C compatible. Tin-silver over tin over nickel over phos bronze terminations.

ELECTRICAL CHARACTERISTICS:

PART	L@0A	L @ lpk	DCR(ohm) MAX			Leakage	Turns ratio		lpk	Out Put
NUMBER	±10% uH	±10% uH	Pri :	Bias	: Sec	L(uH) Max.	Pri : Sec	Pri : Bias	(A)	Pri : Sec
EP10XFS-33L- LF	155	139.5	0.414	0.822	0.036	4.00	1 : 0.190	1 : 0.667	0.65	3.3V ; 2.12A
EP10XFS-50L- LF	155	139.5	0.414	0.822	0.036	3.60	1 : 0.262	1 : 0.667	0.65	5.0V ; 14A
EP10XFS-12L- LF	155	139.5	0.414	0.822	0.036	3.25	1 : 0.667	1 : 0.667	0.65	12V ; 0.6A

- 1) Inductance is for the primary, measured at 250 kHz, 0.1 Vrms, 0 Adc
- 2) DCR for the secondary is per winding
- 3) Leakage inductance is measured between pins 3 and 4 with all other pins shorted
- 4) Turns ratio is with the secondary windings connected in parallel
- 5) Output of the secondary is with the windings connected in parallel. Bias winding output is 12 V, 20 mA
- 6) Ambient temperature range: -40°C to +85°C
- 7) Storage temperature range: Component: -40°C to +85°C
- 8) Resistance to soldering heat: Three reflows at >217°C for 90 seconds (\pm 260°C \pm 5°C for 20 40 seconds allowing parts to cool to room temperature between.